

# Photointerrupter, double-layer mold type

## RPI-246

The RPI-246 is a compact, double-layer mold photointerrupter.

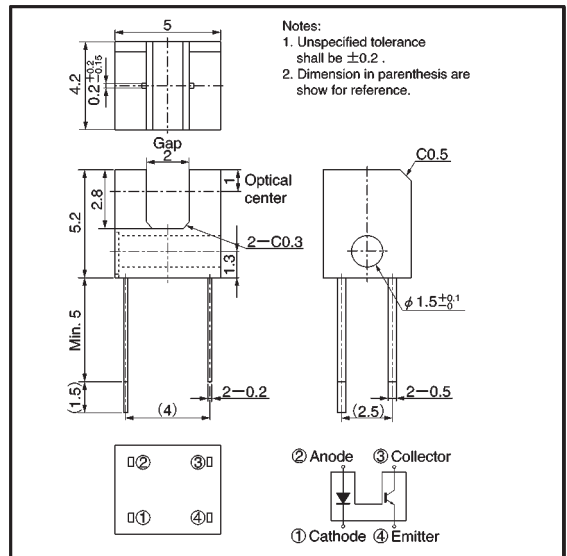
### ●Applications

Floppy disk drives  
Movie equipment  
Cameras  
Printers

### ●Features

- 1) Compact package based on the double-mold.
- 2) Method High resolution (slit width = 0.2 mm).
- 3) Gap between emitter and detector = 2.0 mm.

### ●External dimensions (Units: mm)



### ●Absolute maximum ratings

Parameter		Symbol	Limits	Unit
Input(LED)	Forward current	$I_F$	50	mA
	Reverse voltage	$V_R$	5	V
	Power dissipation	$P_D$	80	mW
Output (photo-transistor)	Collector-emitter voltage	$V_{CEO}$	30	V
	Emitter-collector voltage	$V_{ECO}$	4.5	V
	Collector current	$I_C$	30	mA
	Collector power dissipation	$P_C$	80	mW
Operating temperature		$T_{opr}$	$-25 \sim +85$	$^{\circ}\text{C}$
Storage temperature		$T_{stg}$	$-30 \sim +85$	$^{\circ}\text{C}$

●Electrical and optical characteristics ( $T_c = 25^\circ\text{C}$ )

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input characteristics	Forward voltage	$V_F$	—	1.3	1.6	V	$I_F=50\text{mA}$
	Reverse current	$I_R$	—	—	10	$\mu\text{A}$	$V_R=5\text{V}$
Output characteristics	Dark current	$I_{CEO}$	—	—	0.5	$\mu\text{A}$	$V_{CE}=10\text{V}$
	Peak sensitivity wavelength	$\lambda_P$	—	800	—	nm	—
Transfer characteristics	Collector current	$I_C$	0.35	—	1.2	mA	$V_{CE}=5\text{V}, I_F=20\text{mA}$
	Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	0.4	V	$I_F=20\text{mA}, I_C=0.2\text{mA}$
	Response time	$t_r \cdot t_f$	—	10	—	$\mu\text{s}$	$V_{CC}=5\text{V}, I_F=20\text{mA}, R_L=100\Omega$

## ●Electrical and optical characteristic curves

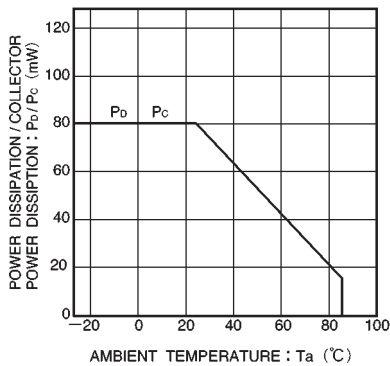


Fig.1 Power dissipation / collector power dissipation vs. ambient temperature

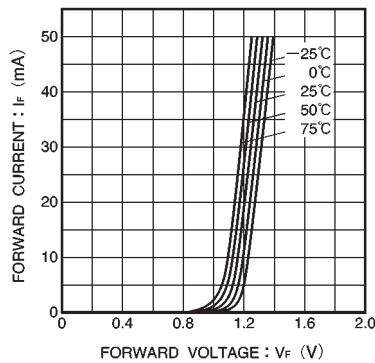


Fig.2 Forward current vs. forward voltage

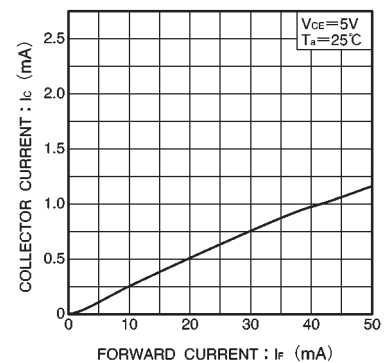


Fig.3 Collector current vs. forward current

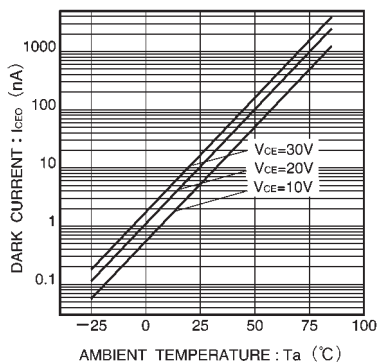


Fig.4 Dark current vs. ambient temperature

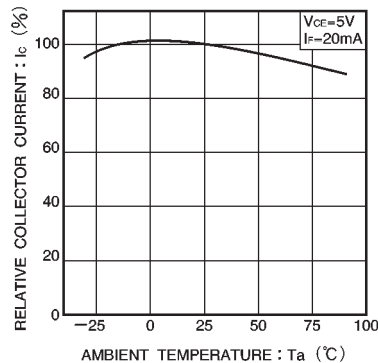


Fig.5 Relative output vs. ambient temperature

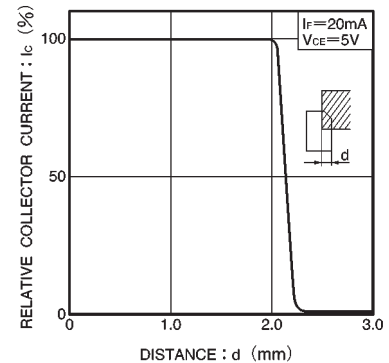


Fig.6 Relative output vs. distance

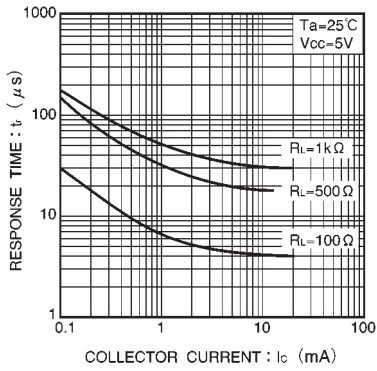


Fig.7 Response time vs. output current

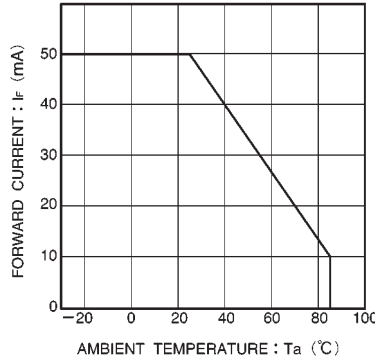


Fig.8 Forward current falloff

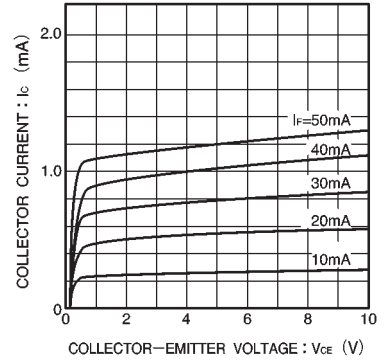
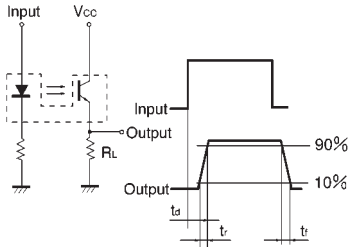


Fig.9 Output characteristics



- $t_d$ : Delay time
- $t_r$ : Rise time (time for output current to rise from 10% to 90% of peak current)
- $t_f$ : Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.10 Response time measurement circuit